AMENDMENTS TO THE SPECIFICATION

Please replace Paragraph [0051] with the following paragraph rewritten in amendment format:

The leak current of the nMOSFET with the structure of Xj = 10 nm is reduced, in effect, by about four digits compared to the leak current of the nMOSFET with <u>the structure of Xj = 25 nm, and by about two digits compared to the leak current of the nMOSFET with <u>the structure of Xj = 20 nm, which are nMOSFETS with the conventional single drain structure.</u></u>